

SEM Studies of Fe₂O₃ Thin-Films on Glass Substrate

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We have investigated thin-films containing nanosized grains of Fe₂O₃ and Fe₂O₃ with Li by the scanning electron microscopy (SEM), impedance spectroscopy (IS) and thermally stimulated currents (TSC) and the Raman spectroscopy. Combining these methods the dependence of structural and electrical properties upon percentage of Li added into the matrix of these metal-oxide films was found. The comparison of IS, TSC and Raman results reveals the increase of grain sizes upon inducing 1% of Li in Fe₂O₃ matrix followed by the decrease of grain sizes in the case of samples with 10% Li, as well as the decrease (increase) of conductivity, respectively. These changes are explained by the structural changes of grains (and grain boundaries) and with the impact of Li⁺ ions in the charge transfers. [1].

Thin-films containing nano-sized grains of Fe₂O₃ are widely used in research into mainly magnetic and electronic devices [1-5]. Their capacity for incorporating lithium ions is important in the construction of galvanic cells of second generation [6-17].

Films of iron oxide derived by the spray method route were investigated by the impedance spectroscopy (IS), Raman spectroscopy, SEM and XRD in order to determine their electrical, structural and morphological properties. Our goal was to establish the relation between electrical and the structural properties in nano-structured Fe₂O₃ and Fe₂O₃:Li films on glass substrate.

IS was applied to measure the resistance of nano-structured Fe₂O₃ films with different contents of lithium. In our previous work [18] TSC spectra, often used in characterization of high resistive or semi-insulating (SI) materials [19, 20] were measured on the same samples, in order to investigate possible defects with deep levels in the forbidden energy gap and to see relation of it to the different percentages of Li. By Raman and XRD measurements, we have determined, besides the hematite nature of our samples, that they are composed of the nano-sized grains, which was also proved by SEM investigation. It was also found that the variation of Li content is related to the changes of the grain sizes.

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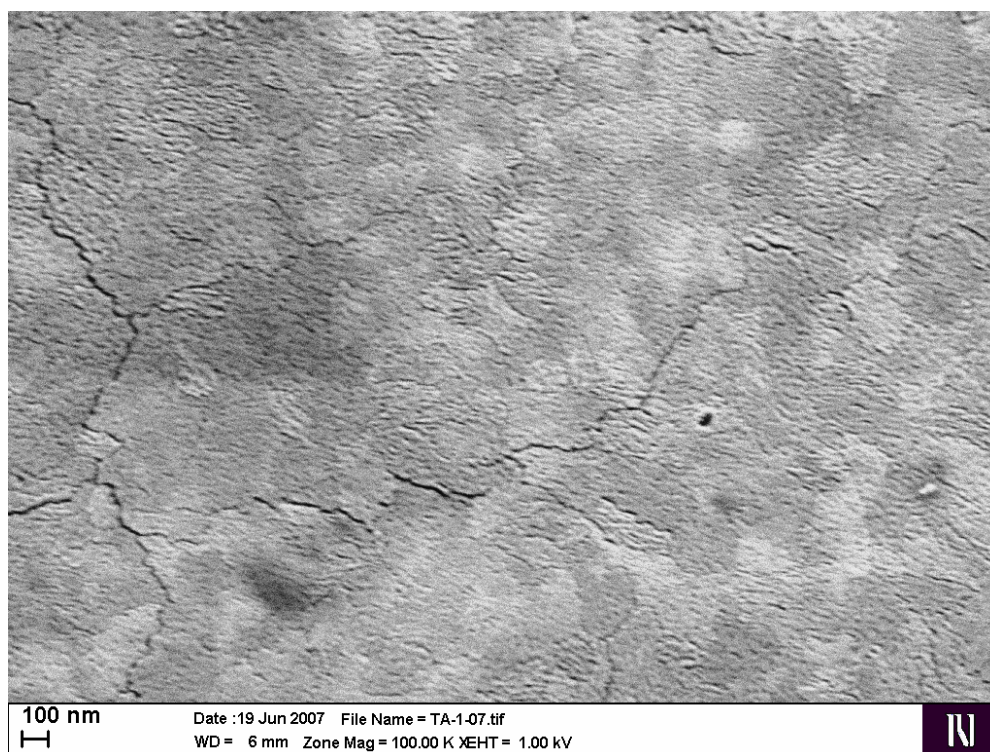


Figure 1. SEM of Fe₂O₃ film.